

# Magnetic Field Tuning of Electron-Electron Interactions

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# Content

Motivation

Design structures to influence e-e- scattering

QCL: Reduce e-e-interaction by magnetic field

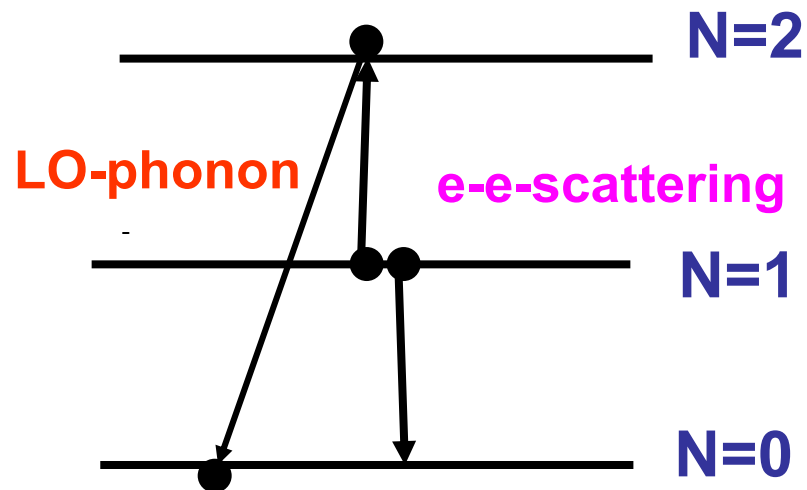
Intersubband plasmons: use e-e interaction to generate a plasmon instability

Experimental work on quantum well samples

Emission results

Summary

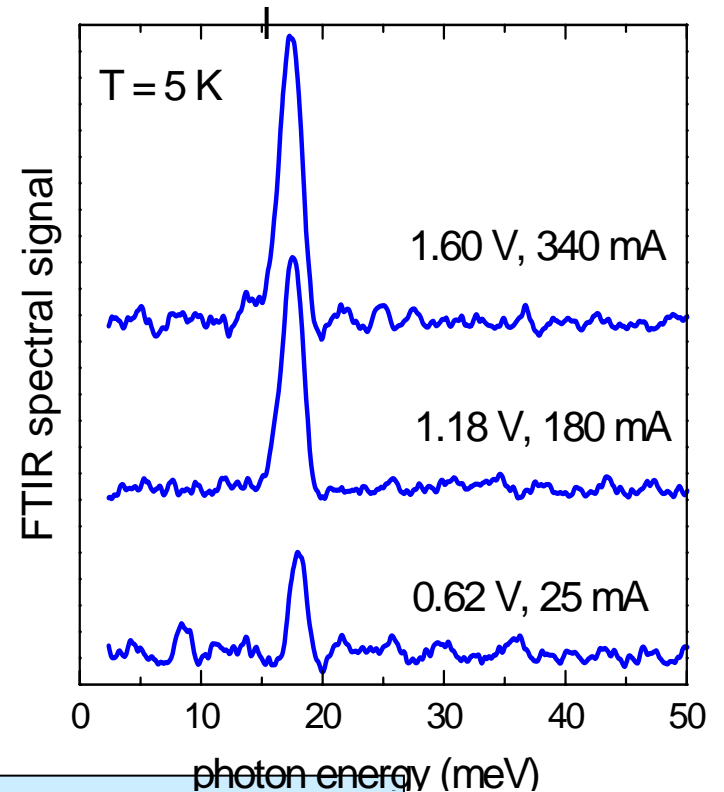
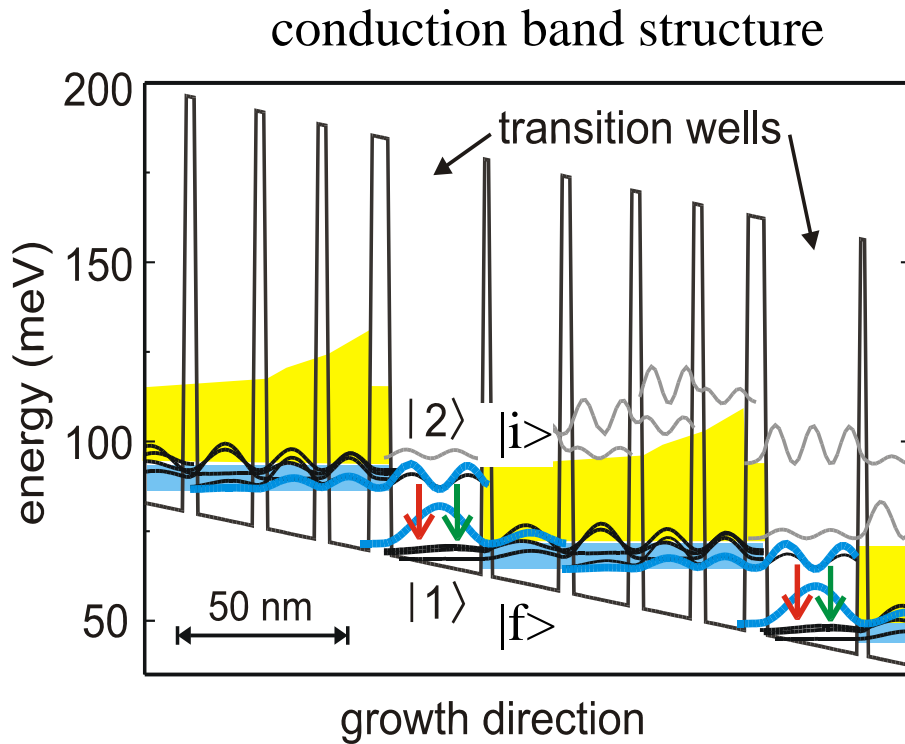
# Joint paper Phys.Rev. 1978 with Bruce on electron-electron scattering rates between Landau levels in bulk InSb, GaAs and CdTe



Quantization only in xy direction  
not in the direction of magnetic field

- energies  $E_0$  and  $E_1$  below the LO-resonance:  
( $E_{if} < 36$  meV)
- non-radiative channel:
  - e-e-scattering
- depopulation of final state  $E_2$  through LO-phonon emission

# THz quantum cascade structure



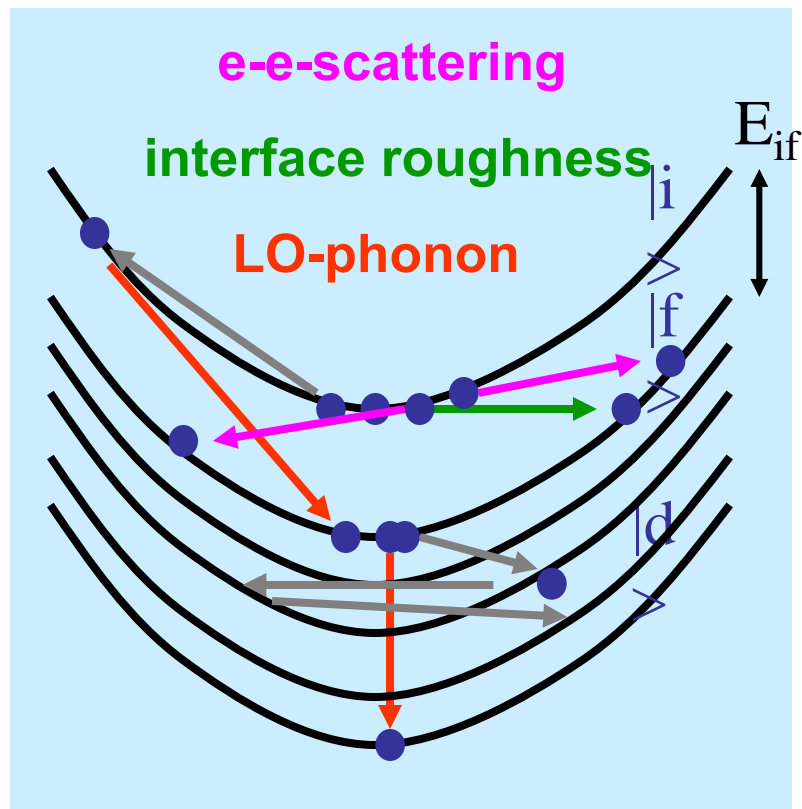
radiative transitions:

$$\hbar\omega = 17 \text{ meV} \quad \nu = 4.1 \text{ THz}$$



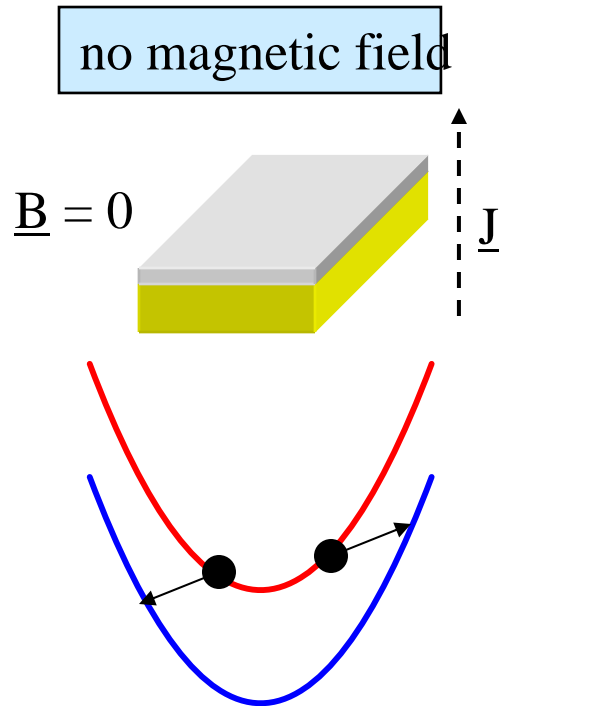
unwanted non-radiative transitions limit the emission efficiency

# Scattering mechanisms - non-radiative processes



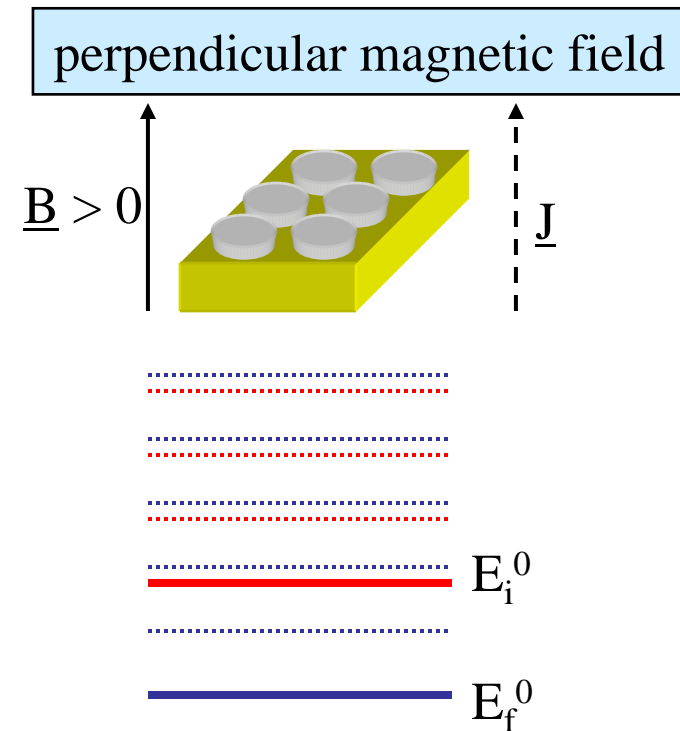
- energy below the LO-resonance:  
( $E_{if} < 36 \text{ meV}$ )
- non-radiative channels:
  - phonon emission from heated electrons
  - interface roughness scattering
  - **e-e-scattering**
- depopulation of final state  $|f\rangle$ 
  - LO-phonon emission
  - intraminiband tunneling extraction

# in-plane quantization / quantum box structure



continuous energy spectrum

$$E_j = E_j^0 + \frac{\hbar^2 k_{//}^2}{2m^*}$$



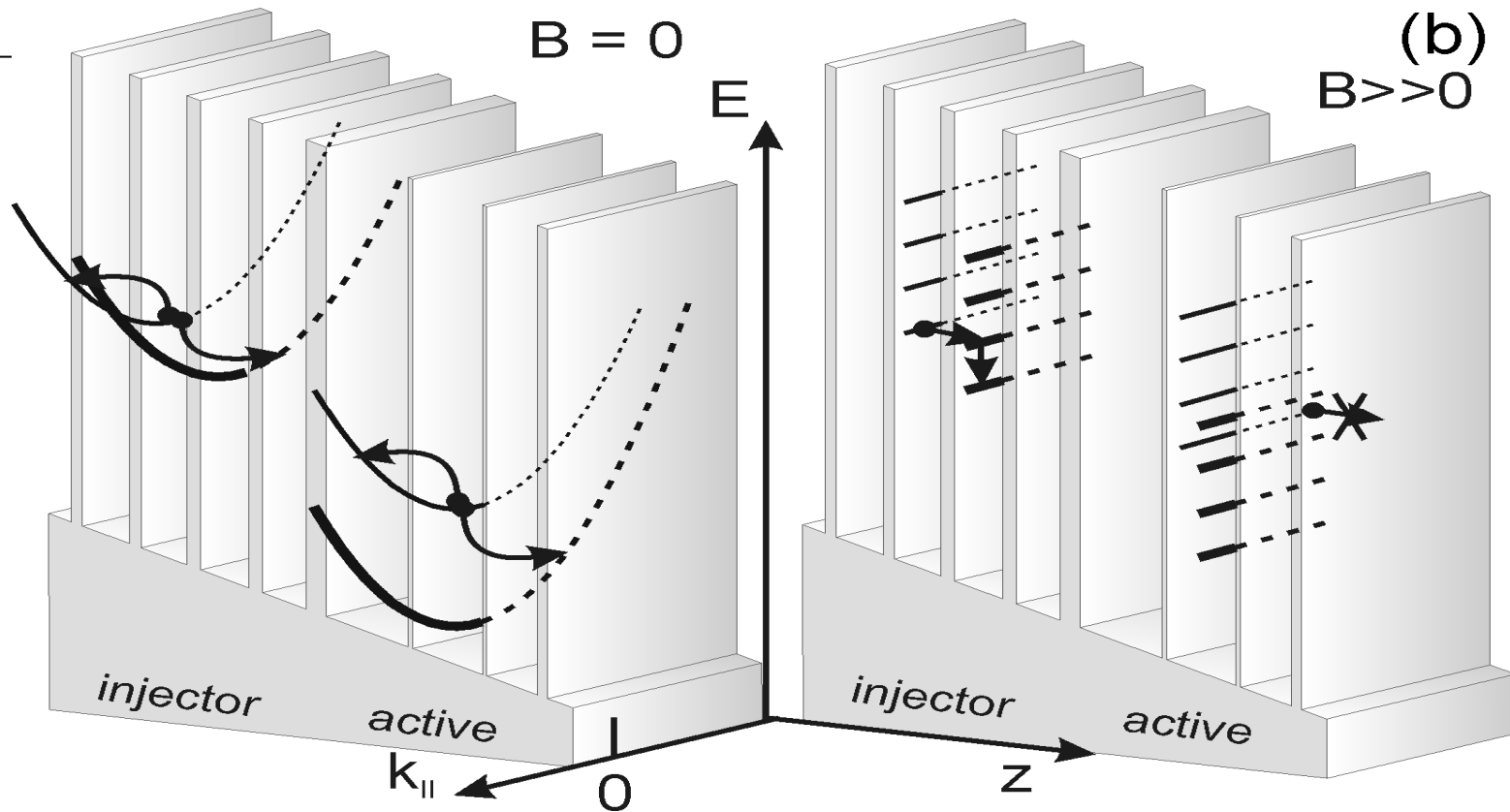
Landau quantization in plane

$$E_{j,N} = E_j^0 + \left(N + \frac{1}{2}\right) \hbar \omega_c$$

$$\omega_c = eB/m^*$$

(intersubband (z) motion and in-plane motion decoupled) complete quantization

# Landau quantization



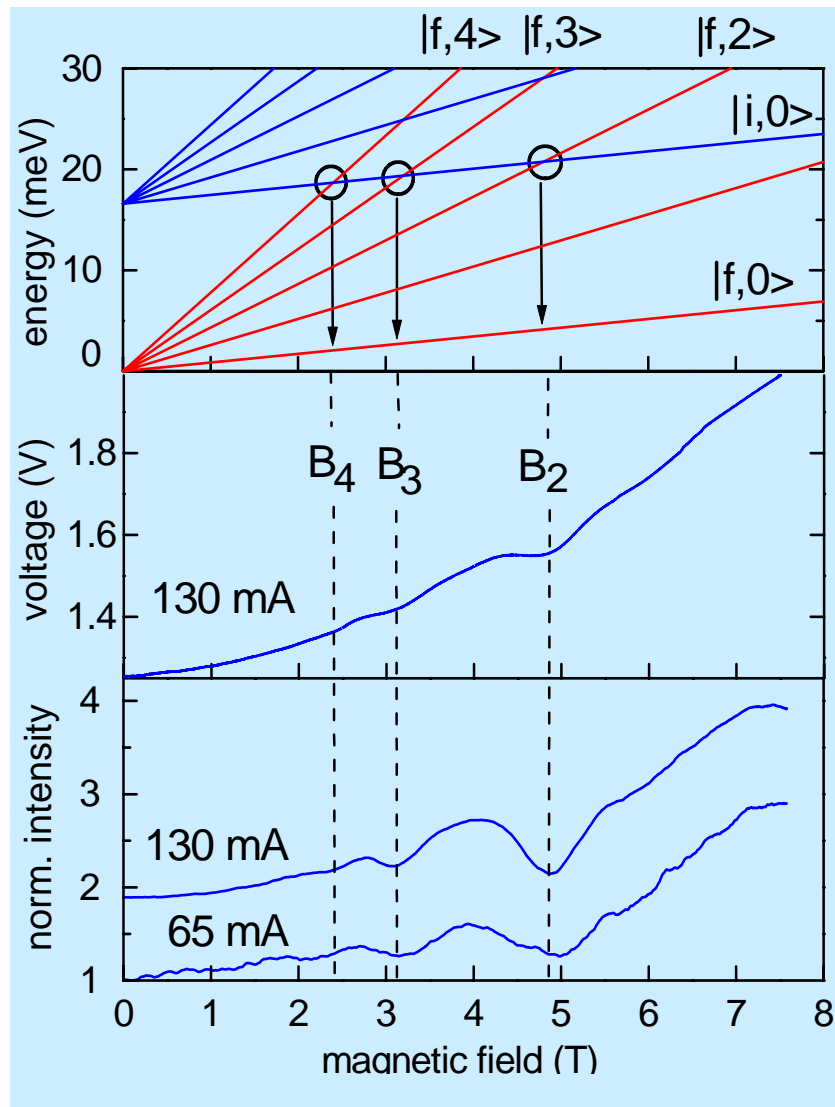
- for active region we want:

$$\frac{\hbar e B}{m^*} N \neq \Delta E_{\text{laser}}$$

- for injector we want:

$$\frac{\hbar e B}{m^*} M = \Delta E_{\text{injector}}$$

# magneto-intersubband oscillations



Ulrich et al., Appl. Phys. Lett. 76, 19 (2000)

opening of a non-radiative channel if:

$$E_i^0 - E_f^0 = \frac{\hbar e B_N}{m^*} N$$

N	$B_N$
(minima)	
2	4.9
3	3.2
4	2.2

$$E_i^0 - E_f^0 = 16.6 \text{ meV}$$

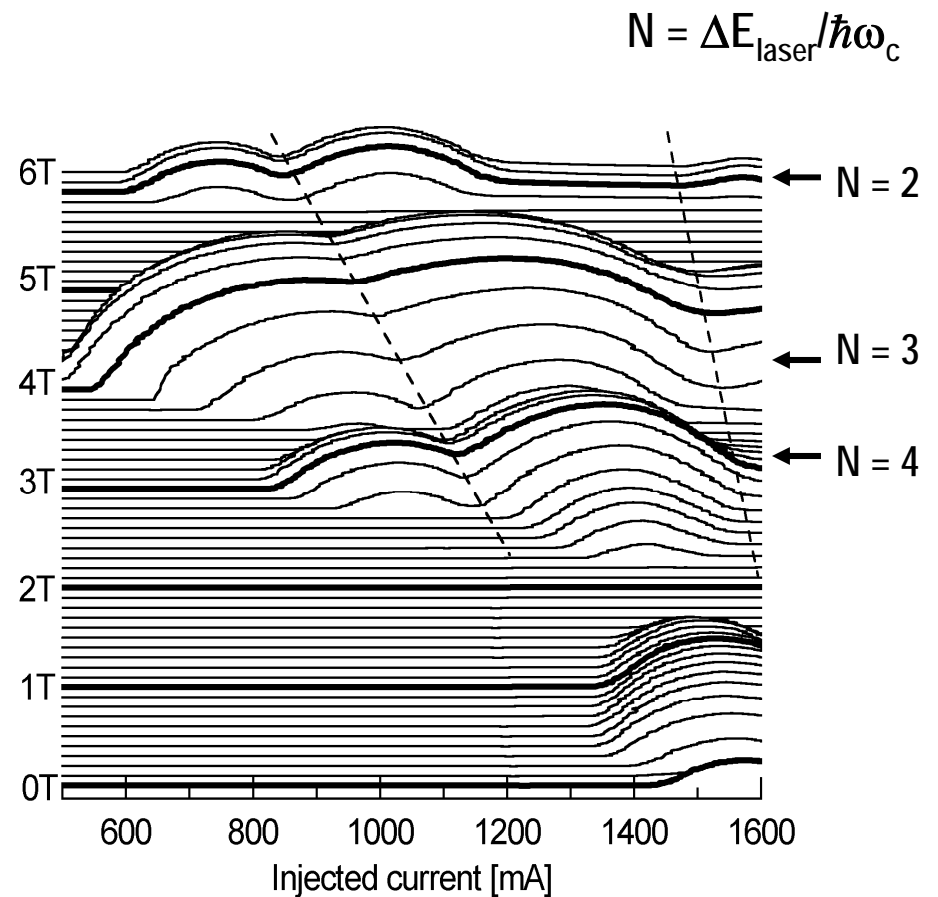
comparable to measured emission photon energy:

$$E_i^0 - E_f^0 = 17.3 \text{ meV}$$

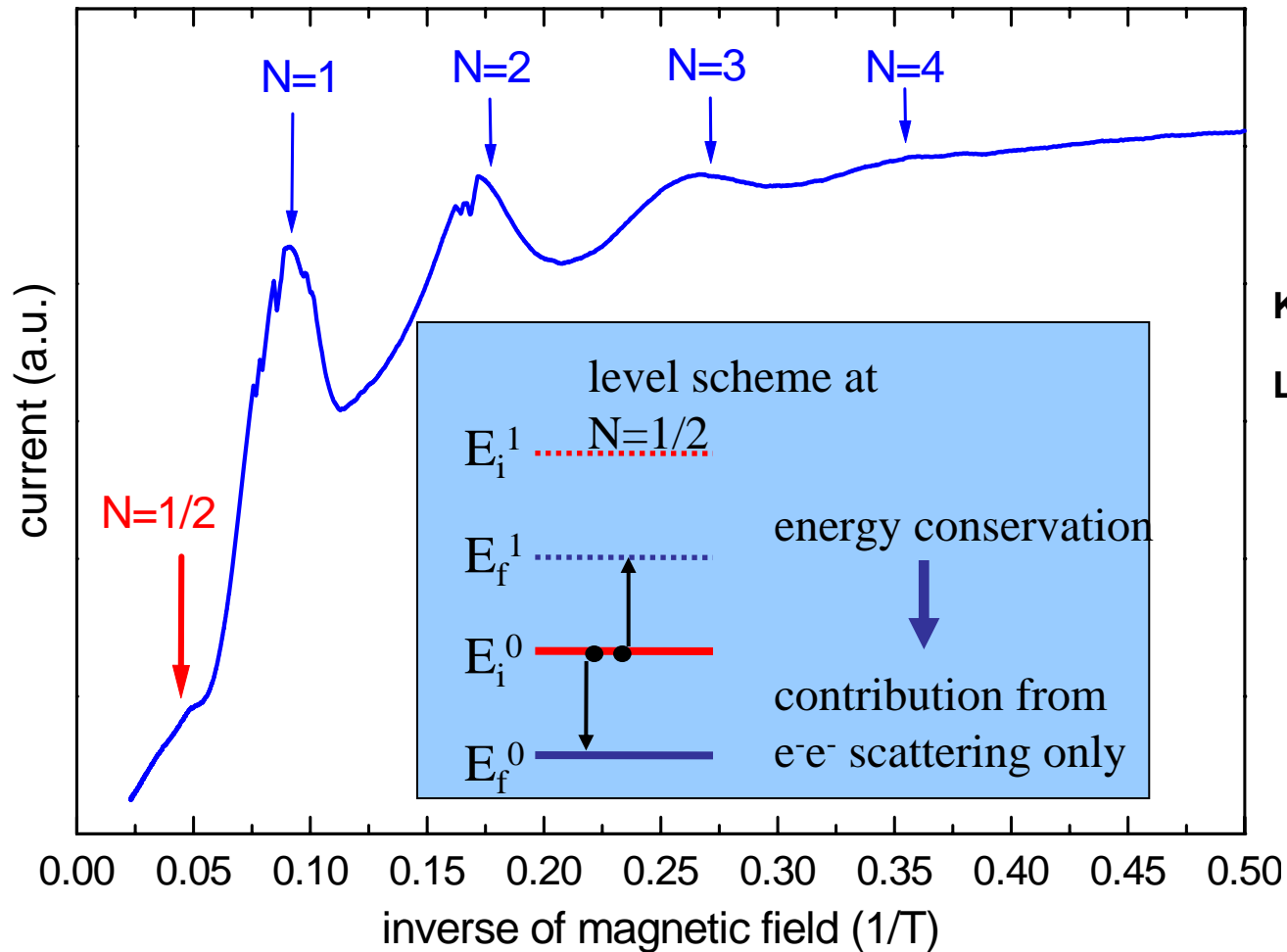
# Laser emission versus current and magnetic field

V. Tamosiunas et al., Appl. Phys. Lett. 83, 3873 (2003).

- Oscillations of the emission intensity
- Intensity minima:  
Are observed for integer  $N$ ,  
due to increased non-radiative relaxation in an active region
- A reduction of the threshold current  
From 1.35A at 0T...  
... to 0.5A at 4.2T
- An increase of the emission intensity  
Maximum at 4.2T  
More than 4 times when compared to 0T



# high magnetic field transport



Kempa et al., Phys. Rev. Lett. 88, 226803(2002).

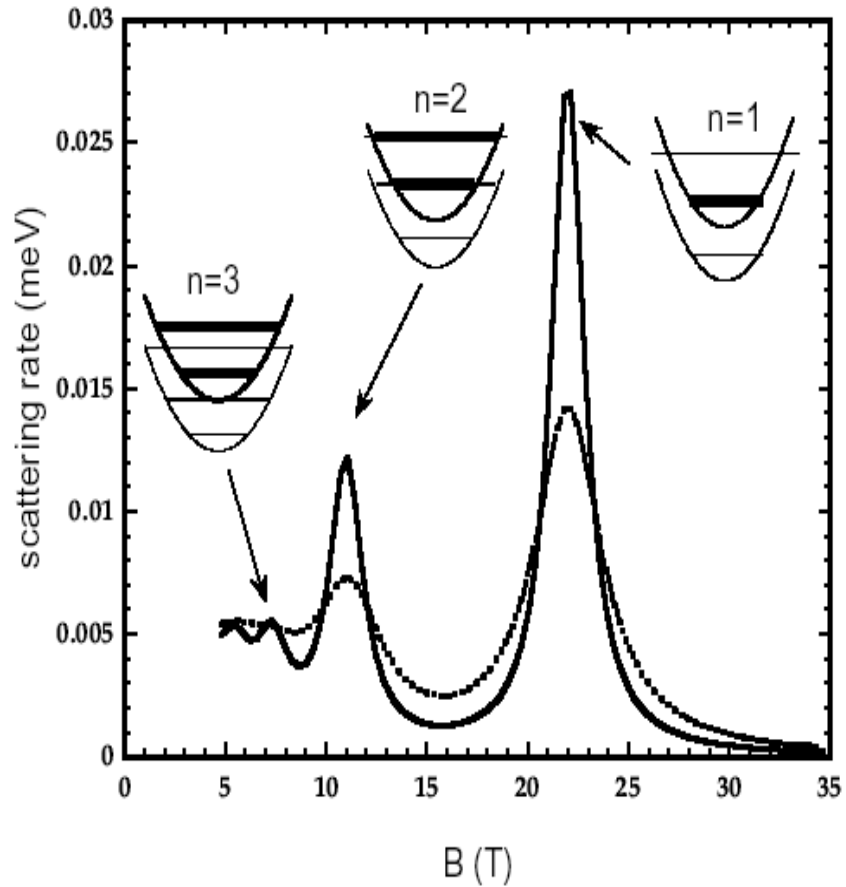
- half integer peaks are indication for e-e scattering mechanism

# Non-resonant intersubband electron-electron scattering

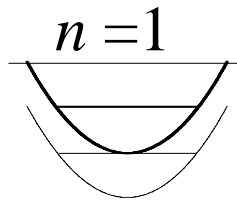


Theory shows that el-el scattering rate peaks for ALL  $n$  (odd and even)

**Sample:** TU Vienna  
**Measurements:** Boston College (M. Naughton's group) and in Vienna



# Experimental results



$$\hbar \omega_c = \frac{2\Delta}{n} \quad n = 1, 2, 3, \dots$$

G. Scalari et al. Phys. Rev. Letters, 93, 237403, (2004).

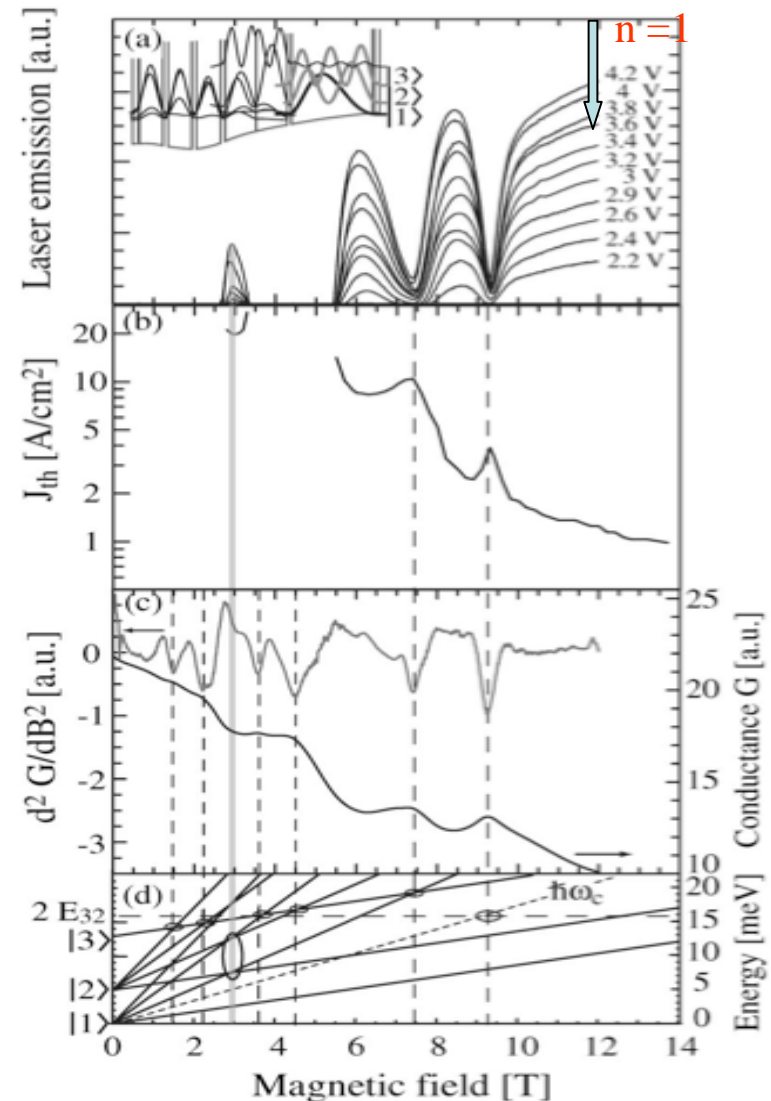
THz Cascade Laser

Fully confirmed the theory and experimental result of

K. Kempa et al. Phys. Rev. Letters, 88, 226803, (2002).

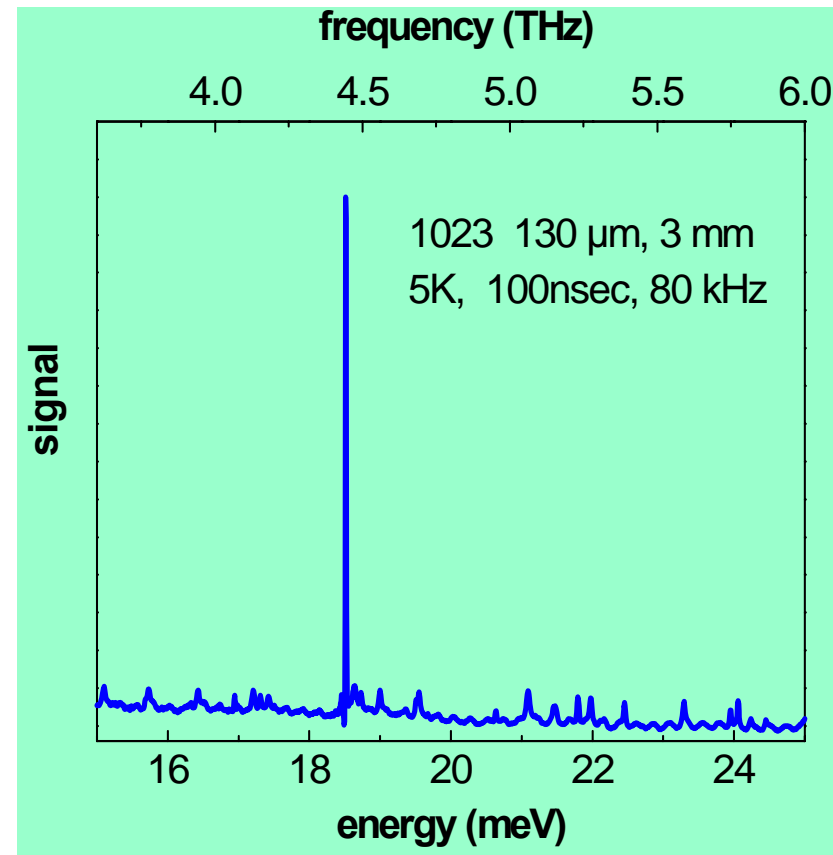
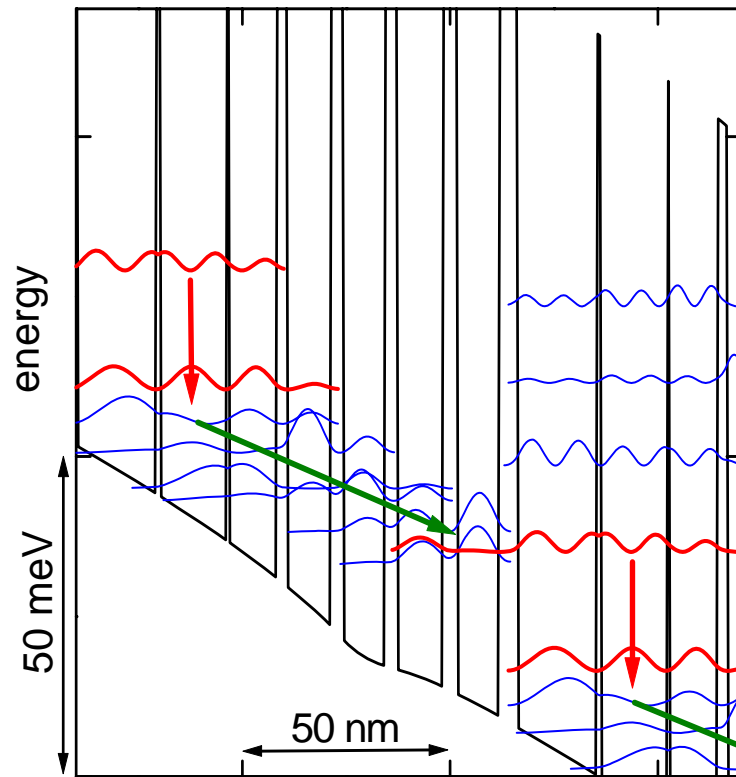


El-el scattering is a primary process in this structure



# THz QCL

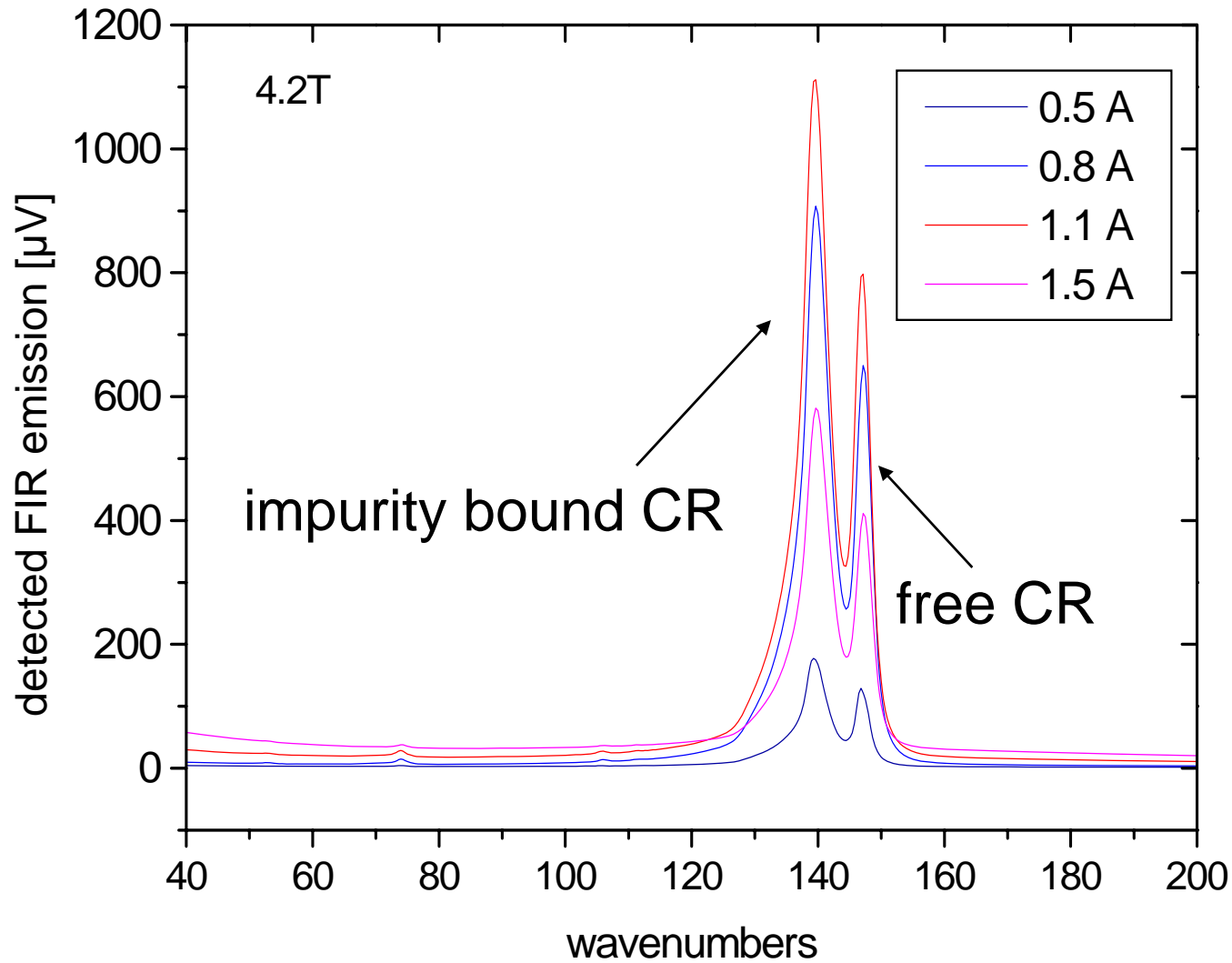
## Miniband design 15 meV



Köhler et al., Nature 417, 156( 2002)

in collaboration with R. Colombelli, C. Gmachl,  
K. West, L. Pfeiffer, F. Cappaso, LUCENT

# Application: InSb cyclotron resonance spectra



## Conclusions for QCL work

- The intensity enhancement and the **extreme** threshold current reduction with magnetic field are attributed to:
  - the suppression of nonradiative Auger-intersubband transitions by Landau-quantization of the in-plane electron motion,
  - the modulation of the injection rate via resonant inter-Landau-level transfer

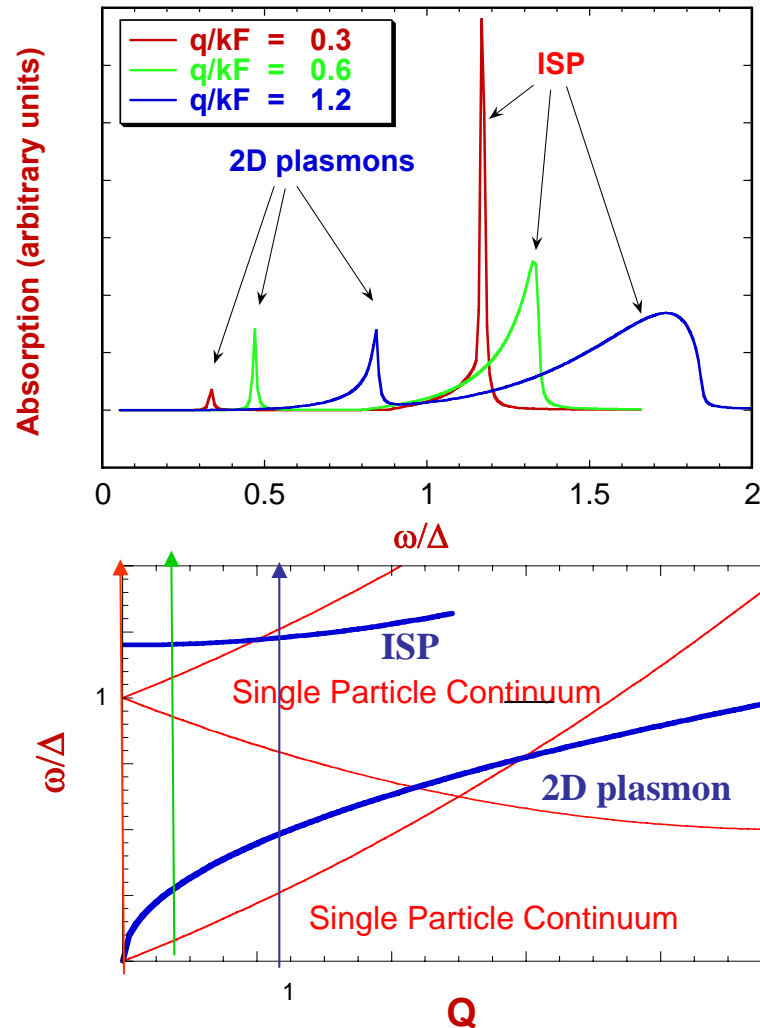


# Intersubband Plasmons

- **Theoretical aspects**
- **Experiments on a „three level system“ quantum well**

# Intersubband plasmons (ISP) in quantum wells

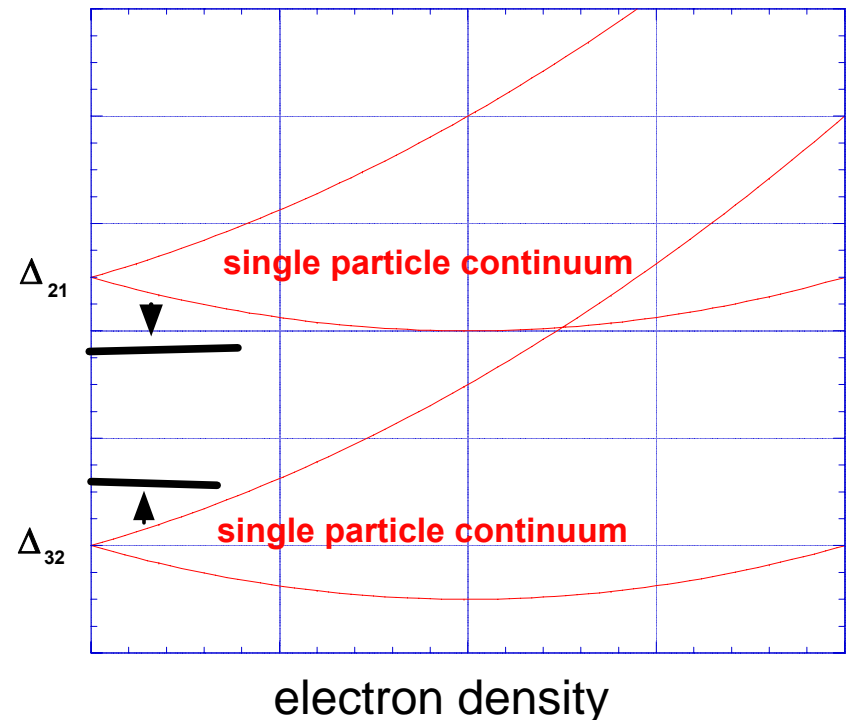
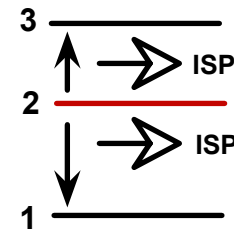
## 2 subband case



- ISP is a hybrid excitation  
It involves a single electron scattering between the subbands and a collective excitation (plasmon) of all electrons in the QW.
- ISP is *depolarization shifted* so that  $\omega > \Delta$ , for the “normal” subband occupation  $n_1 > n_2$ .
- For a reversed subband occupation ( $n_2 > n_1$ ) the sign of the depolarization shift also reverses.

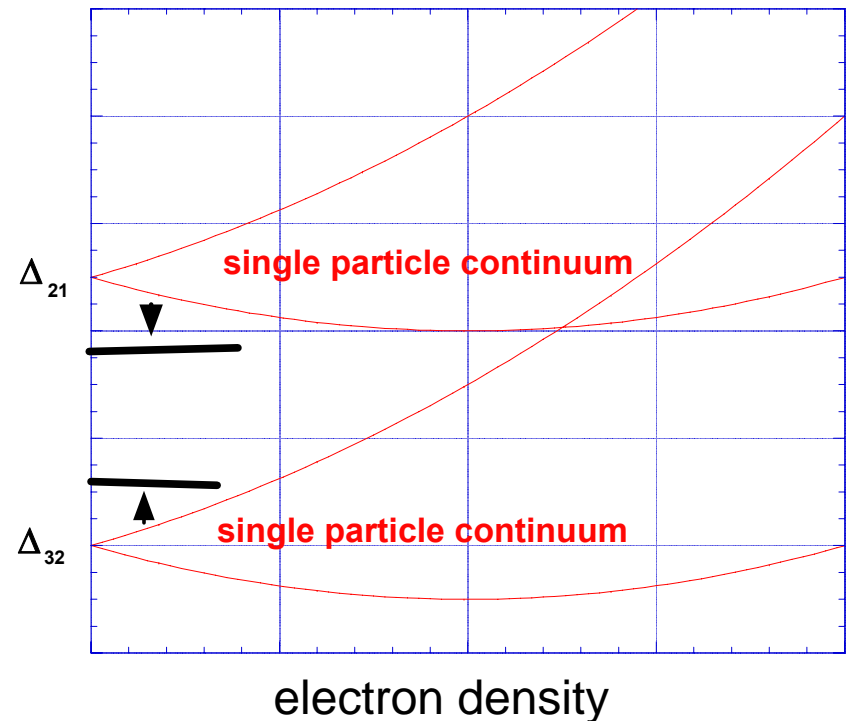
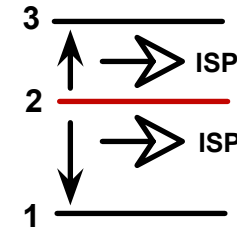
# ISP in quantum wells (3 subband case: 2nd filled)

- There are now two ISP, one depolarization shifted downwards and the other upwards, from the corresponding inter-subband separations.
- By reducing  $\Delta_{21}$ - $\Delta_{32}$  and/or increasing electron density on subband 2 we can cause the two ISP to cross.

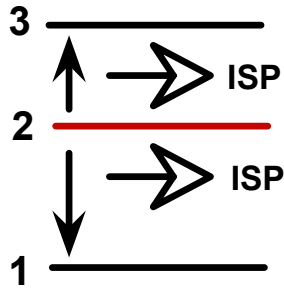


# ISP in quantum wells (3 subband case: 2nd filled)

- The two ISP modes **attractively cross**.
- Pair of ISP modes forms, **one unstable**
- ( $\omega'' > 0$ ): thus the candidate for **stimulated emission**.
- Since formation of each ISP pair involves transfer of two electrons out of subband 2, this process can be also viewed as a **resonant electron-electron scattering**.
- The rate of this process is  $\gamma = \omega''$ .



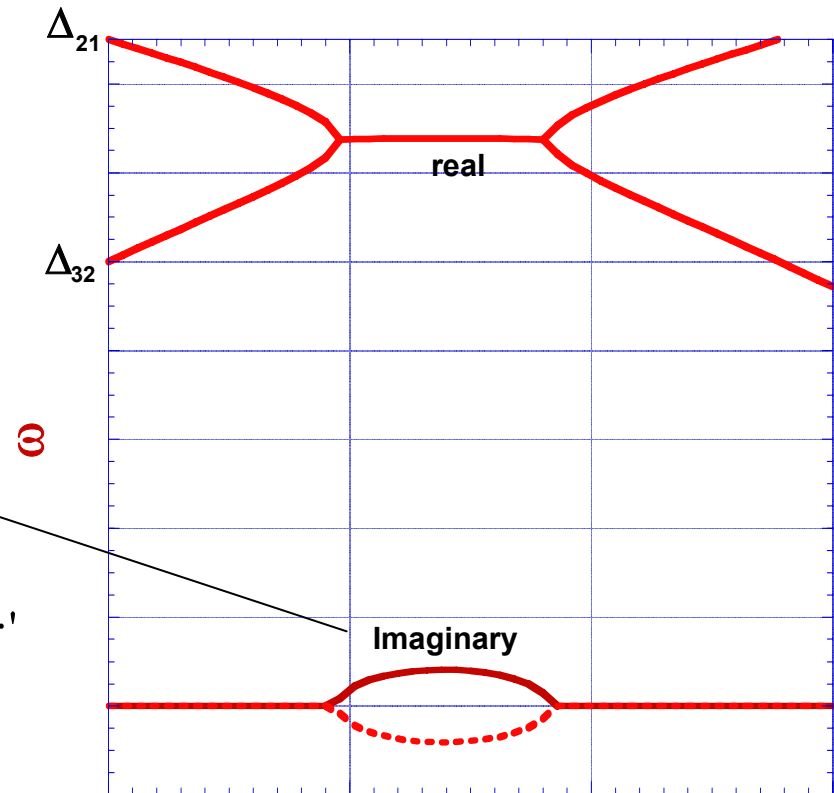
## Stimulated ISP emission as resonant electron-electron scattering



$$\gamma = \text{Im}(\omega) = 2(f_2 - f_1)(f_3 - f_2) |G_{12,23}|$$

$$G_{12,23} = \int \psi_1(r)\psi_2(r) \frac{1}{|r-r'|} \psi_2(r')\psi_3(r') dr dr'$$

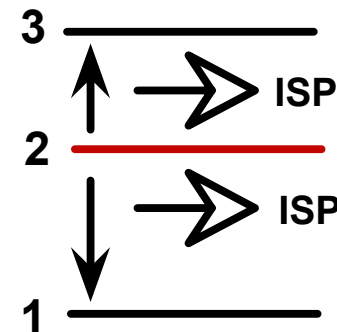
Analogue of plasma instabilities in gaseous plasmas



Electron density on subband 2

# Realistic situation:

- Population inversion between subband 3 and subband 2 is possible by extracting carriers from subband 2 with a resonant RTD
- Subband 1 (populated by LO phonon emission) has a higher population than subband 2

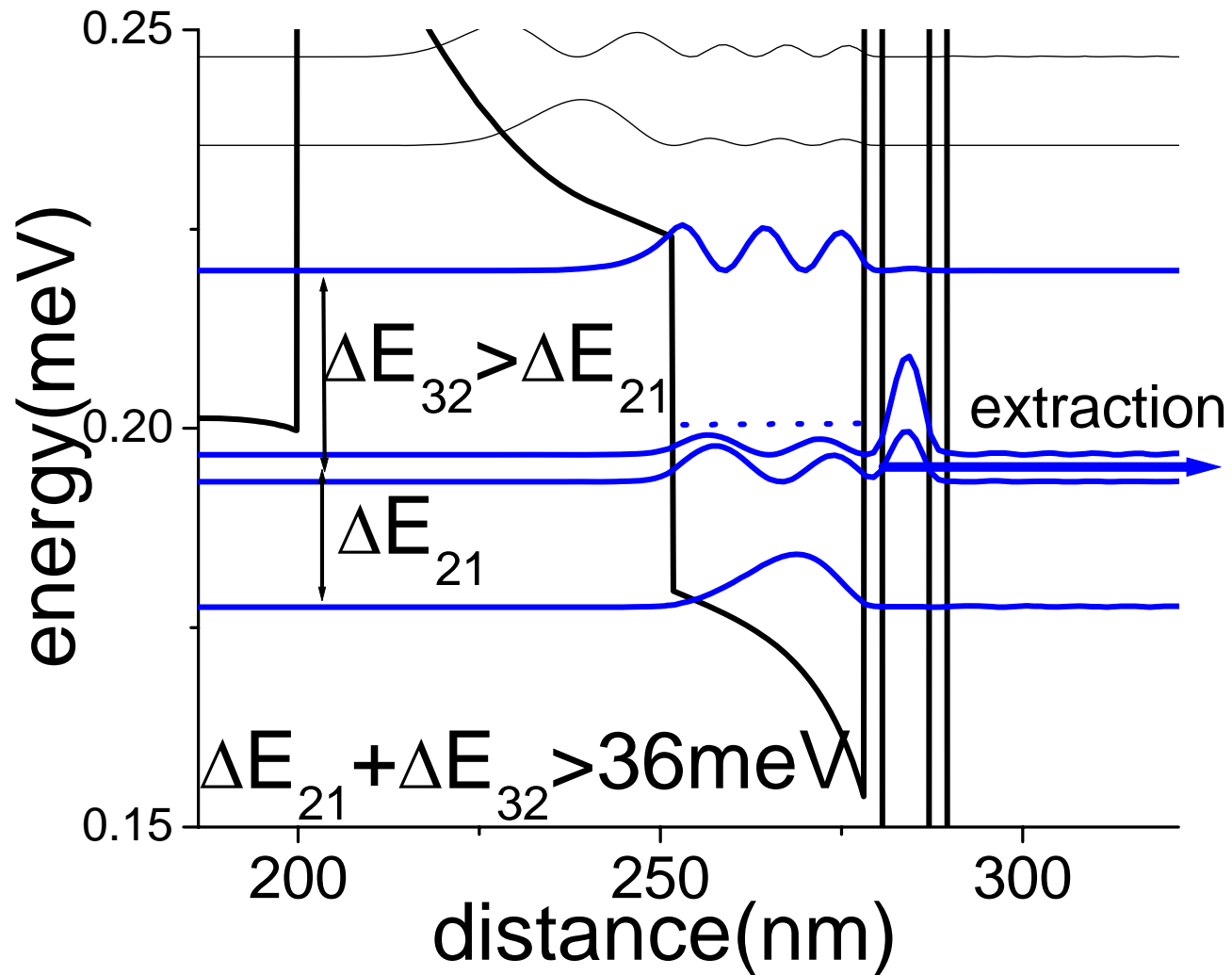


# Experimental results

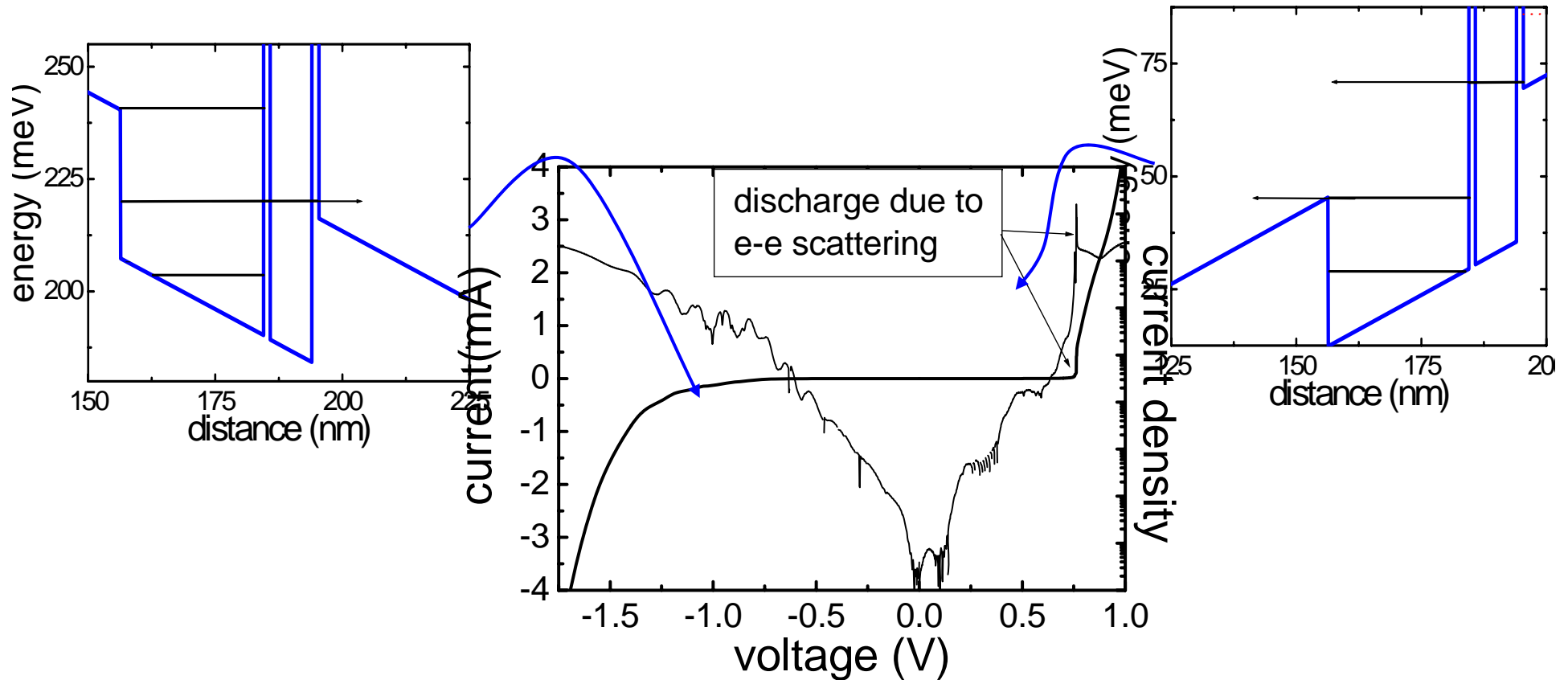
IV –curves  
magnetic field effects

Emission spectra  
with step scan Fourier spectrometer

# Experimental three level system



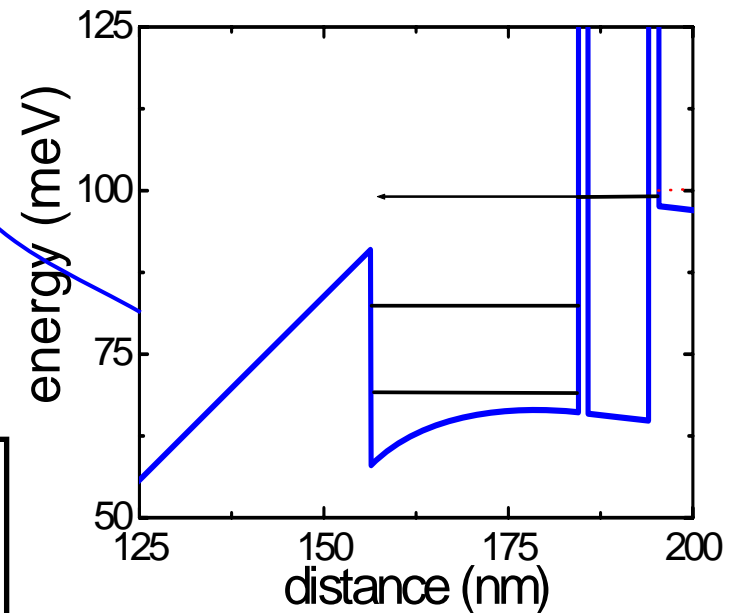
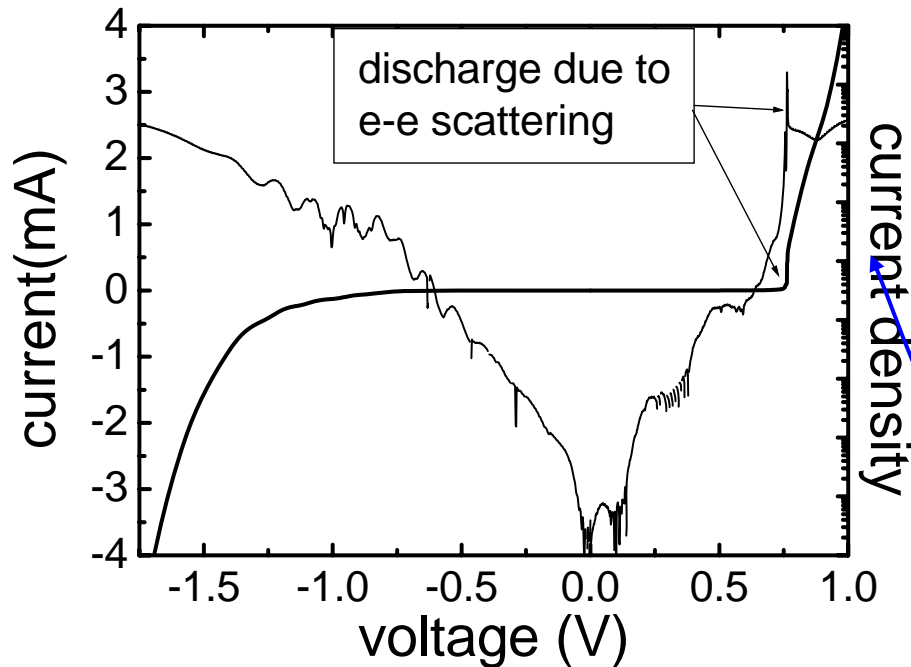
# transport behaviour @ $B=0T$



**Negative bias: RTD acts as extractor**

**Positive bias: RTD acts as injector**

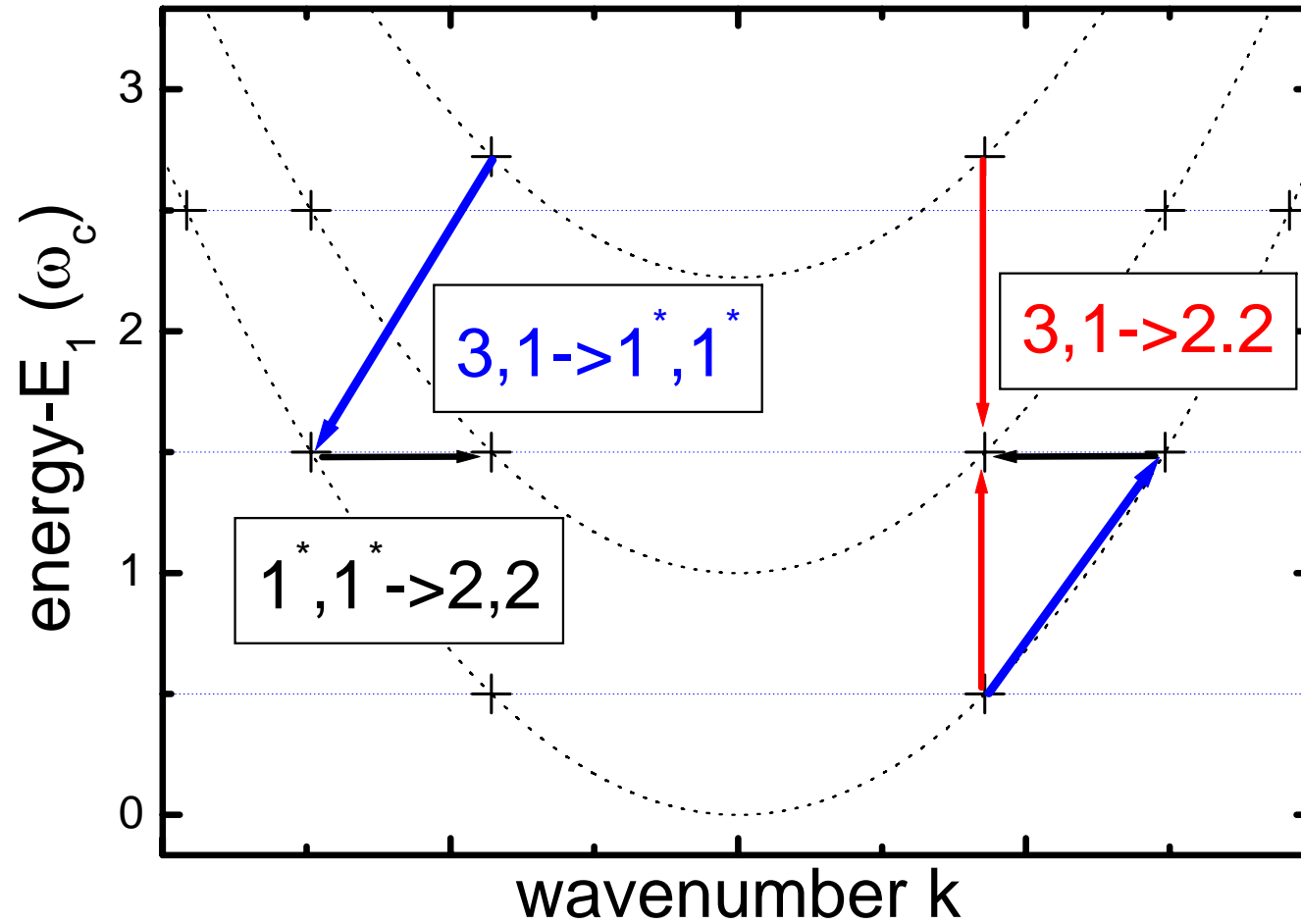
# transport behaviour @ B=0T



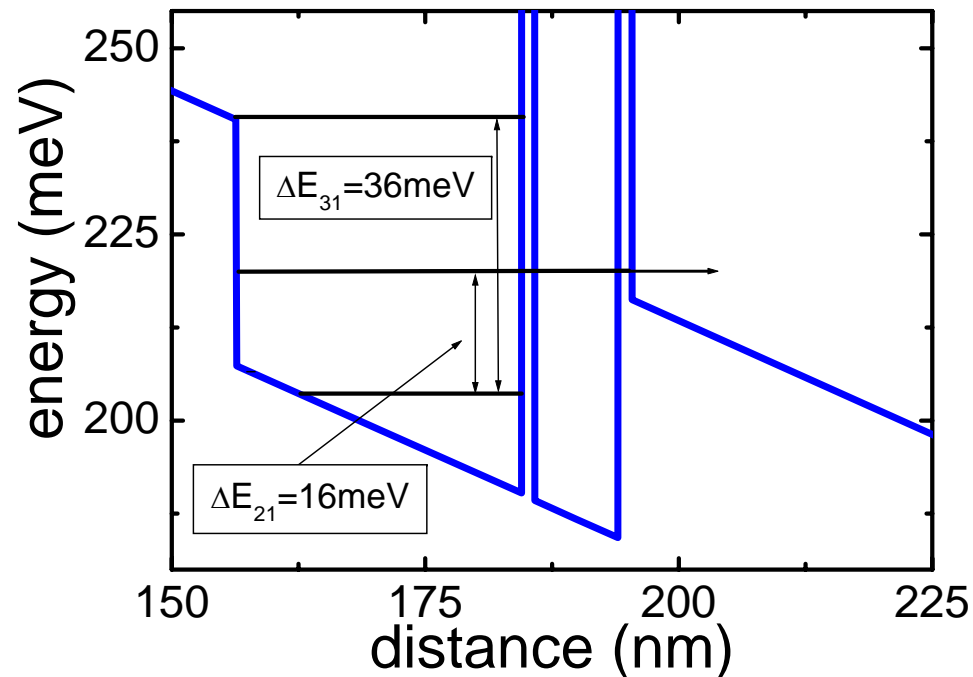
**We have evidence that at a given bias of  $V=753\text{mV}$ : The  $\text{In}_{0.05}\text{Ga}_{0.95}\text{As}$  well becomes discharged due to e-e scattering**

**This is confirmed in magnetic field measurements**

# e-e scattering mechanisms



# magnetic field current studies



Increasing  $B$  results in decreasing current

Additional possible scattering mechanism results in a current increase at  $B=4.5\text{T}$  and  $B=9\text{T}$  ( $\hbar\omega_c=15.5\text{meV}$ ) respectively  $B=5.5\text{T}$  and  $B=10.5\text{T}$  ( $\hbar\omega_c=18\text{meV}$ ) when the Landau splitting is equal to the intersubband splitting

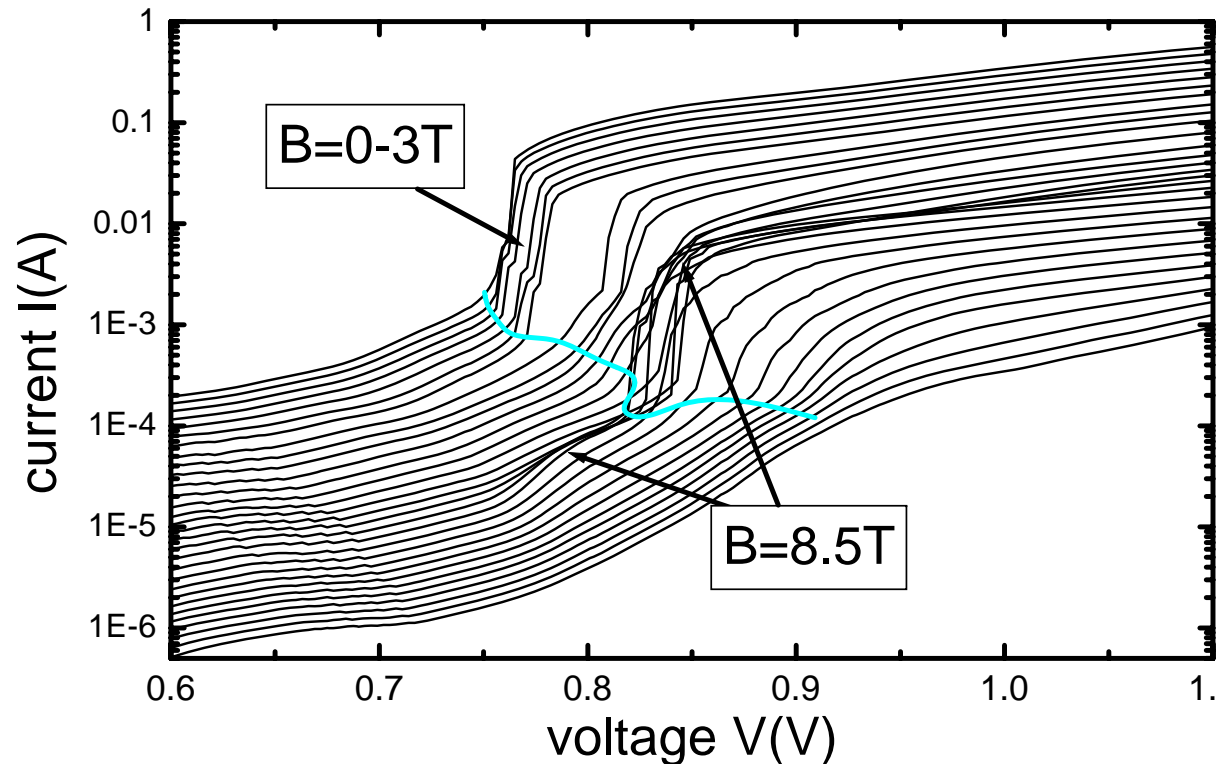
This indicates that e-e scattering ( $3,1 \rightarrow 2,2$ ) is an important mechanism in this structure

## magnetic field (positive bias)

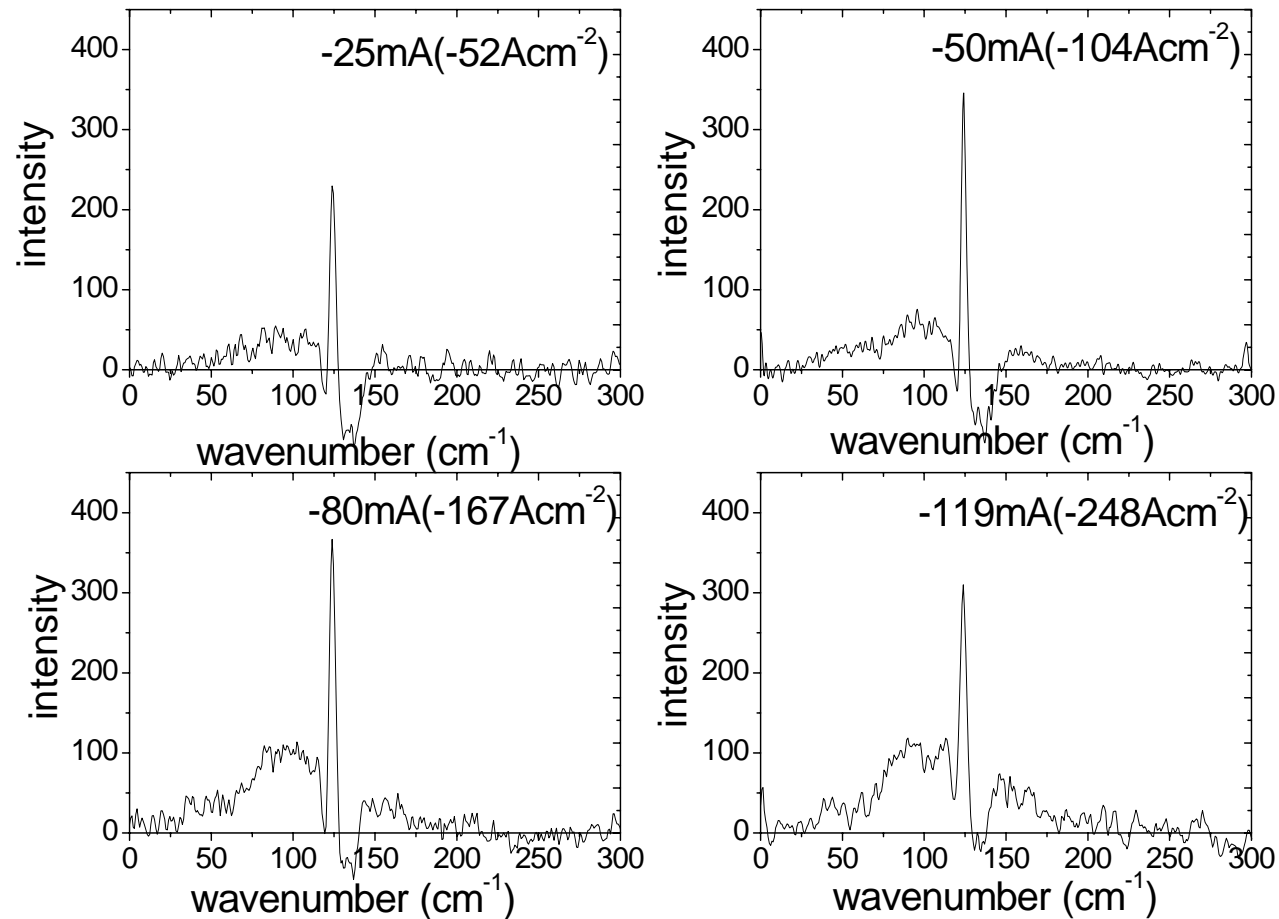
at current onset around  $V=752\text{meV}$  a strong influence of  $B$  observed:

- The onset shifts to higher  $V$  with increasing  $B$  up to  $V=846\text{meV}$  ( $B=7\text{T}$ )
- Between  $B=7\text{T}$  and  $B=8.5\text{T}$  the onset shifts to lower voltages ( $V=820\text{meV}$ )

•Around  $B=8.5\text{T}$  a small peak occurs in the bias range between  $V=750\text{meV}$  and  $V=820\text{meV}$ , indicating filling of the second energy level without efficient extraction

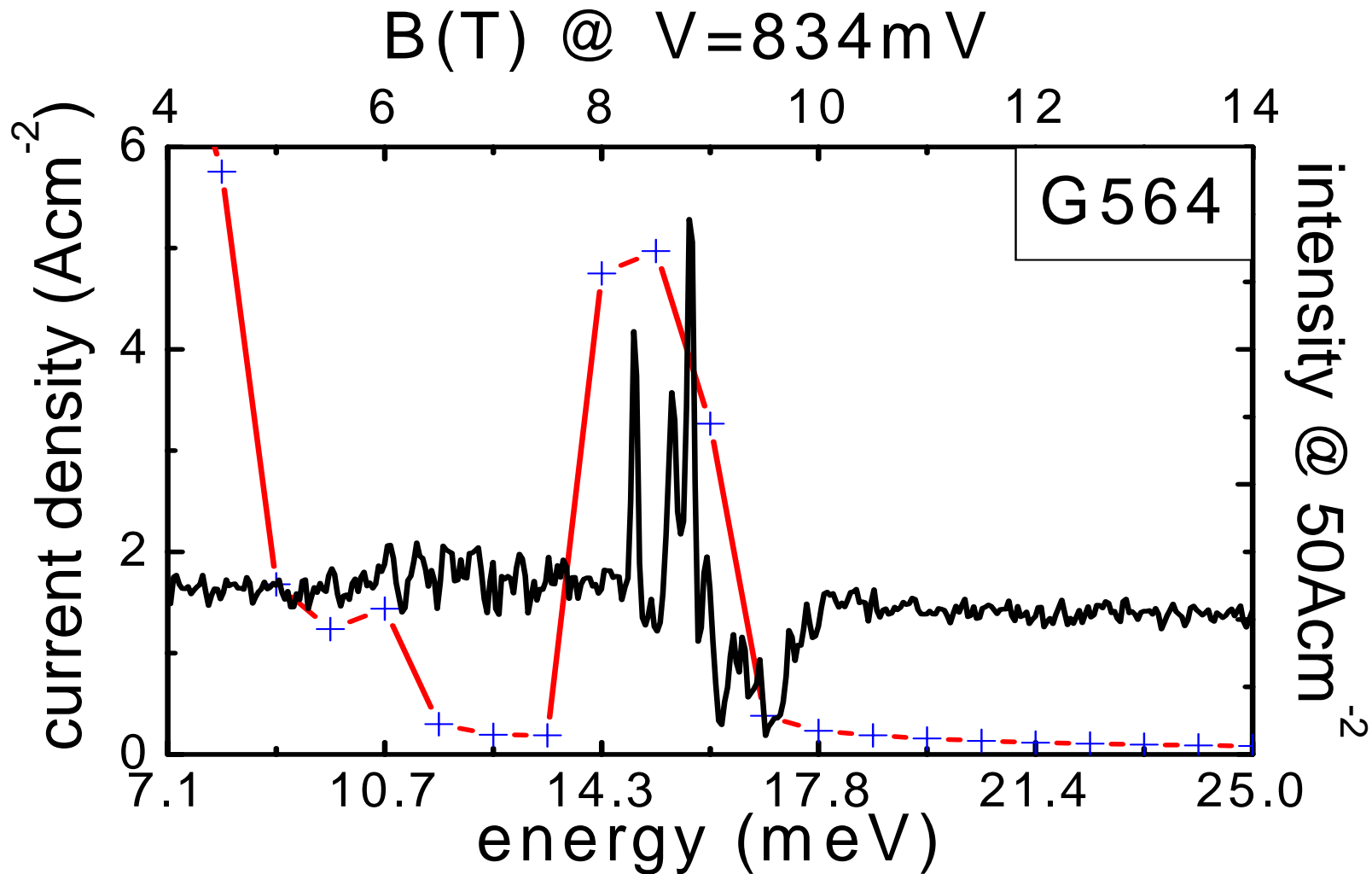


# W2: Intersubband resonance: emission results

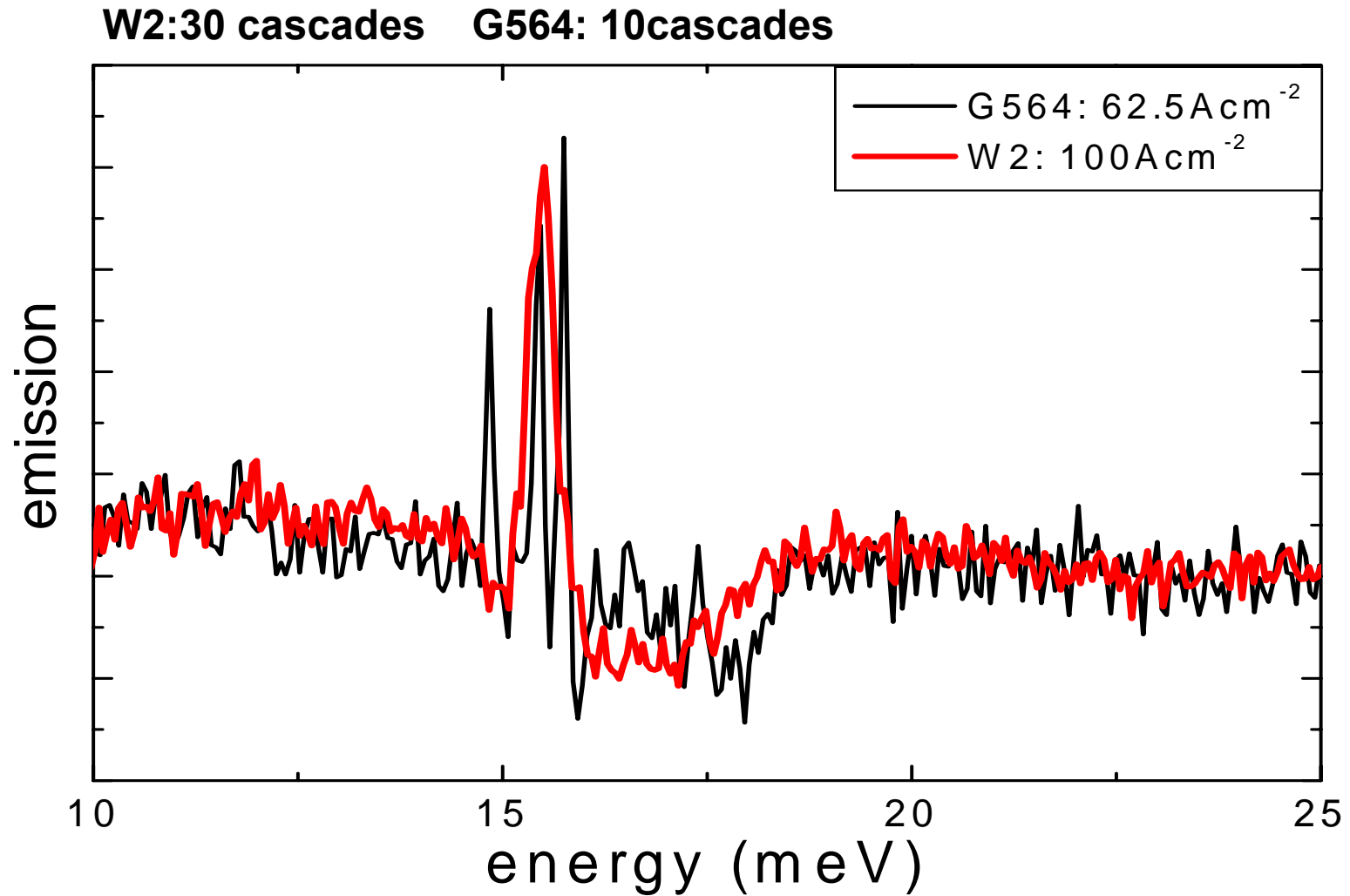


device area:  $A=5e-4\text{cm}^2$

# G564: spectral behaviour (ISP-resonance)



# Comparison of emission results at ISP resonance



# Summary

- QCL intensity enhancement:
- extreme threshold current reduction with magnetic field
  
- ISP-Emission of THz radiation:
- signature of Plasma Instability
- Magnetis field studies confirm the resonant e-e-process
- The emission persisted up to 70K
  
- Goal is to realize a coherent THz source based on stimulated plasma oszillations
- Work on improved structures is planed